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# BIPOLAR ANALOG INTEGRATED CIRCUIT

# $\mu$ PC29Mxx Series

#### THREE TERMINAL LOW DROPOUT VOLTAGE REGULATOR

The  $\mu$ PC29Mxx series of low dropout voltage three terminal positive regulators is constructed with PNP output transistor. The  $\mu$ PC29Mxx series feature the ability to source 0.5 A of output current with a low dropout voltage of typically 0.5 V.

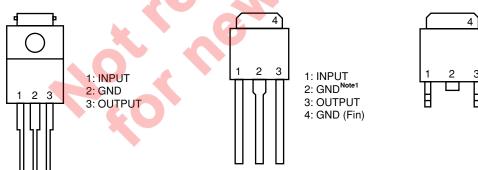
The power dissipation of the  $\mu$ PC29Mxx series can be drastically reduced compared with the conventional three terminal positive voltage regulators that is constructed with NPN output transistor. Also, this series corresponds to the low voltage output (3.0 V, 3.3 V) which is not in the conventional low dropout regulators ( $\mu$ PC24MxxA series).

#### **FEATURES**

- Output current in excess of 0.5 A
- Low dropout voltage
   VDIF = 0.5 V TYP. (Io = 0.5 A)
- On-chip over-current and thermal protection circuit
- On-chip output transistor safe operating area protection circuit

#### <R> PIN CONFIGURATIONS (Marking Side)

μPC29MxxHF Series: Isolated TO-220 (MP-45G) μPC29MxxHB Series: SC-64 (MP-3) μPC29MxxT Series: SC-63 (MP-3Z)



Notes 1. No.2 pin and No.4 fin are common GND.

2. No.2 pin is cut. No.2 pin and No.4 fin are common GND.

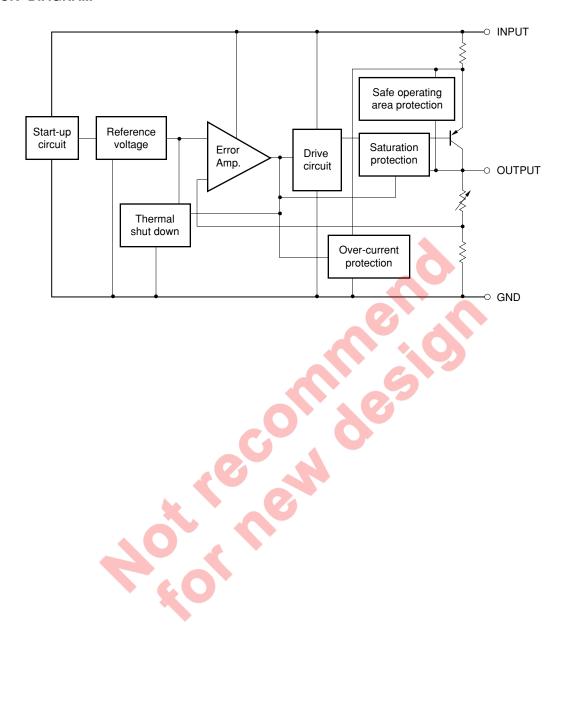
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3: OUTPUT

4: GND (Fin)



#### **BLOCK DIAGRAM**





#### <R> ORDERING INFORMATION

Part Number	Package	Output Voltage	Marking	
μPC29M03HF	Isolated TO-220 (MP-45G)	3.0 V	29M03	
μPC29M03HB	SC-64 (MP-3)	3.0 V	29M03	
μPC29M03T	SC-63 (MP-3Z)	3.0 V	29M03	
μPC29M33HF	Isolated TO-220 (MP-45G)	3.3 V	29M33	
μРС29М33НВ	SC-64 (MP-3)	3.3 V	29M33	
μPC29M33T	SC-63 (MP-3Z)	3.3 V	29M33	
μPC29M05HF	Isolated TO-220 (MP-45G)	5.0 V	29M05	
μPC29M05HB	SC-64 (MP-3)	5.0 V	29M05	
μPC29M05T	SC-63 (MP-3Z)	5.0 V	29M05	
μPC29M06HF	Isolated TO-220 (MP-45G)	6.0 V	29M06	
μPC29M06HB	SC-64 (MP-3)	6.0 V	29M06	
μPC29M06T	SC-63 (MP-3Z)	6.0 V	29M06	
μPC29M07HF	Isolated TO-220 (MP-45G)	7.0 V	29M07	
μPC29M07HB	SC-64 (MP-3)	7.0 V	29M07	
μPC29M07T	SC-63 (MP-3Z)	7.0 V	29M07	
μPC29M08HF	Isolated TO-220 (MP-45G)	8.0 V	29M08	
μPC29M08HB	SC-64 (MP-3)	8.0 V	29M08	
μPC29M08T	SC-63 (MP-3Z)	8.0 V	29M08	
μPC29M09HF	Isolated TO-220 (MP-45G)	9.0 V	29M09	
μPC29M09HB	SC-64 (MP-3)	9.0 V	29M09	
μPC29M09T	SC-63 (MP-3Z)	9.0 V	29M09	
μPC29M10HF	Isolated TO-220 (MP-45G)	10.0 V	29M10	
μPC29M10HB	SC-64 (MP-3)	10.0 V	29M10	
μPC29M10T	SC-63 (MP-3Z)	10.0 V	29M10	
μPC29M12HF	Isolated TO-220 (MP-45G)	12.0 V	29M12	
μPC29M12HB	SC-64 (MP-3)	12.0 V	29M12	
μPC29M12T	SC-63 (MP-3Z)	12.0 V	29M12	

Remark Tape-packaged products have the symbol -E1, or -E2 suffixed to the part number. Pb-free products have the symbol -AZ, or -AY suffixed to the part number. Refer to the following table for details.



Part Number Note1	Package	Packege Type
μPC29MxxHF	Isolated TO-220 (MP-45G)	Packed in envelop
μPC29MxxHF-AZ Note2	Isolated TO-220 (MP-45G)	Packed in envelop
μPC29MxxHB	SC-64 (MP-3)	Packed in envelop
μPC29MxxHB-AZ Note2	SC-64 (MP-3)	Packed in envelop
μPC29MxxHB-AY Note3	SC-64 (MP-3)	Packed in envelop
μPC29MxxT-E1	SC-63 (MP-3Z)	16 mm wide embossed taping
		<ul> <li>Pin 1 on draw-out side</li> </ul>
		• 2000 pcs/reel
μPC29MxxT-E1-AZ Note2	SC-63 (MP-3Z)	16 mm wide embossed taping
		<ul> <li>Pin 1 on draw-out side</li> </ul>
		• 2000 pcs/reel
μPC29MxxT-E1-AY Note3	SC-63 (MP-3Z)	16 mm wide embossed taping
		<ul> <li>Pin 1 on draw-out side</li> </ul>
		• 2000 pcs/reel
μPC29MxxT-E2	SC-63 (MP-3Z)	<ul> <li>16 mm wide embossed taping</li> </ul>
		<ul> <li>Pin 1 at take-up side</li> </ul>
		• 2000 pcs/reel
μPC29MxxT-E2-AZ Note2	SC-63 (MP-3Z)	• 16 mm wide embossed taping
		<ul> <li>Pin 1 at take-up side</li> </ul>
		• 2000 pcs/reel
μPC29MxxT-E2-AY Note3	SC-63 (MP-3Z)	• 16 mm wide embossed taping
		Pin 1 at take-up side
		• 2000 pcs/reel

Notes 1. xx stands for symbols that indicate the output voltage.

2. Pb-free (This product does not contain Pb in the external electrode.)

401

3. Pb-free (This product does not contain Pb in the external electrode, Sn100% plating.)

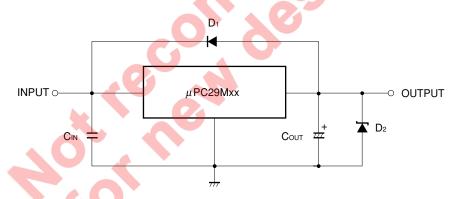
#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C, Unless otherwise specified.)

Parameter	Symbol	Rating				
ratametei	Syllibol	μPC29MxxHF	μPC29MxxHB, μPC29MxxT	Unit		
Input Voltage	Vin	2	0	V		
Internal Power Dissipation (Tc = 25°C) Note	Рт	15	10	W		
Operating Ambient Temperature	Та	–30 to	0 +85	°C		
Operating Junction Temperature	TJ	–30 to	+150	°C		
Storage Temperature	T <sub>stg</sub>	–55 to	+150	°C		
Thermal Resistance (Junction to Case)	Rth (J-C)	7	12.5	°C/W		
Thermal Resistance (Junction to Ambient)	Rth (J-A)	65	125	°C/W		

**Note** Internally limited. When the operating junction temperature rises above 150°C, the internal circuit shuts down the output voltage.

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

#### TYPICAL CONNECTION



CIN :  $0.1~\mu\text{F}$  or higher. Be sure to connect CIN to prevent parasitic oscillation. Set this value according to the length of the line between the regulator and the INPUT pin. Use of a film capacitor or other capacitor with first-rate voltage and temperature characteristics is recommended. If using a laminated ceramic capacitor, it is necessary to ensure that CIN is  $0.1~\mu\text{F}$  or higher for the voltage and temperature range to be used.

Cout : 47 μF or higher. Be sure to connect Cout to prevent oscillation and improve excessive load regulation. Place Cin and Cout as close as possible to the IC pins (within 1 to 2 cm). Also, use an electrolytic capacitor with low impedance characteristics if considering use at sub-zero temperatures.

D<sub>1</sub> : If the OUTPUT pin has a higher voltage than the INPUT pin, connect a diode.

D<sub>2</sub>: If the OUTPUT pin has a lower voltage than the GND pin, connect a Schottky barrier diode.

Caution Make sure that no voltage is applied to the OUTPUT pin from external.



#### RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Type Number	MIN.	TYP.	MAX.	Unit
Input Voltage	VIN	μPC29M03	4		16	
		μPC29M33	4.3		16	
		μPC29M05	6		16	
		μPC29M06	7		16	
		μPC29M07	8		16	V
		μPC29M08	9		18	
		μPC29M09	10		18	
		μPC29M10	11		18	
		μPC29M12	13		18	
Output Current	lo	all	0		0.5	Α
Operating Ambient Temperature	TA	all	-30		+85	°C
Operating Junction Temperature	TJ	all	-30		+125	°C

#### **ELECTRICAL CHARACTERISTICS**

 $\mu$ PC29M03 (T<sub>J</sub> = 25°C, V<sub>IN</sub> = 5 V, Io = 350 mA, C<sub>IN</sub> = 0.22  $\mu$ F, C<sub>OUT</sub> = 47  $\mu$ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		2.88	3.0	3.12	
		$\begin{array}{c} 0^{\circ}C \leq T_{J} \leq 125^{\circ}C,  4.0  V \leq V_{IN} \leq 16  V, \\ 0  A \leq I_{O} \leq 350  mA \\ \\ 0^{\circ}C \leq T_{J} \leq 125^{\circ}C,  0  A \leq I_{O} \leq 0.5  A \end{array}$	2.85		3.15	V
Line Regulation	REGIN	4.0 V ≤ V <sub>IN</sub> ≤ 16 V		7	30	mV
Load Regulation	REG∟	0 A ≤ lo ≤ 0.5 A		8	30	mV
Quiescent Current	IBIAS	lo = 0 A		1.8	4.0	A
		lo = 0.5 A		17	30	mA
Startup Quiescent Current	IBIAS (s)	V <sub>IN</sub> = 2.95 V, Io = 0 A		7	30	mA
	60	V <sub>IN</sub> = 2.95 V, Io = 0.5 A			80	IIIA
Quiescent Current Change	$\Delta l_BIAS$	$0^{\circ}\text{C} \le \text{T}_\text{J} \le 125^{\circ}\text{C}, \ 4.0 \ \text{V} \le \text{V}_\text{IN} \le 16 \ \text{V}$		3.2	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		51		$\mu V_{r.m.s.}$
Ripple Rejection	R·R	f = 120 Hz, 4.0 V ≤ V <sub>IN</sub> ≤ 16 V	48	64		dB
Dropout Voltage	VDIF	0°C ≤ T <sub>J</sub> ≤ 125°C, lo = 0.5 A		0.5	1.0	V
Short Circuit Current	IO short	V <sub>IN</sub> = 4.5 V	0.65	1.0	1.5	A
		V <sub>IN</sub> = 16 V		0.6		A
Peak Output Current	lO peak	V <sub>IN</sub> = 4.5 V	0.7	1.0	1.5	_
		V <sub>IN</sub> = 16 V	0.6	0.9	1.5	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}C \le T_{J} \le 125^{\circ}C$ , $I_{O} = 5 \text{ mA}$		-0.3		mV/°C



 $\mu$ PC29M33 (T<sub>J</sub> = 25°C, V<sub>IN</sub> = 5 V, Io = 350 mA, C<sub>IN</sub> = 0.22  $\mu$ F, C<sub>OUT</sub> = 47  $\mu$ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		3.17	3.3	3.43	
		$ \begin{array}{c} 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \; 4.3 \; V \leq V_{IN} \leq 16 \; V, \\ 0 \; A \leq Io \leq 350 \; mA \end{array} $	3.14		3.46	V
		$0^{\circ}C \le T_{J} \le 125^{\circ}C$ , $0 A \le I_{O} \le 0.5 A$			3.43	
Line Regulation	REGIN	4.3 V ≤ V <sub>IN</sub> ≤ 16 V		8	33	mV
Load Regulation	REG∟	0 A ≤ Io ≤ 0.5 A		10	33	mV
Quiescent Current	IBIAS	Io = 0 A		1.8	4.0	A
		Io = 0.5 A		15	30	mA
Startup Quiescent Current	IBIAS (s)	Vin = 3.1 V, lo = 0 A		9	30	A
		Vin = 3.1 V, lo = 0.5 A			80	mA
Quiescent Current Change	Δlbias	0°C ≤ T <sub>J</sub> ≤ 125°C, 4.3 V ≤ V <sub>IN</sub> ≤ 16 V		2.9	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		56		$\mu V_{r.m.s.}$
Ripple Rejection	R·R	f = 120 Hz, 4.3 V ≤ V <sub>IN</sub> ≤ 16 V	48	64		dB
Dropout Voltage	VDIF	0°C ≤ T <sub>J</sub> ≤ 125°C, lo = 0.5 A		0.5	1.0	٧
Short Circuit Current	IO short	V <sub>IN</sub> = 4.5 V	0.7	1.1	1.5	_
		Vin = 16 V	(2)	0.6		A
Peak Output Current	IO peak	V <sub>IN</sub> = 4.5 V	0.7	1.2	1.5	
		V <sub>IN</sub> = 16 V	0.6	1.0	1.5	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	0°C ≤ T <sub>J</sub> ≤ 125°C, lo = 5 mA		-0.4		mV/°C
40	O					



 $\mu$ PC29M05 (T<sub>J</sub> = 25°C, V<sub>IN</sub> = 8 V, Io = 350 mA, C<sub>IN</sub> = 0.22  $\mu$ F, C<sub>OUT</sub> = 47  $\mu$ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		4.8	5.0	5.2	
		$ 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 6 \ V \leq V_{IN} \leq 16 \ V, $ $ 0 \ A \leq I_{O} \leq 350 \ mA $	4.75		5.25	V
		$0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 0 \ A \leq I_{O} \leq 0.5 \ A$				
Line Regulation	REGIN	6 V ≤ V <sub>IN</sub> ≤ 16 V		26	50	mV
Load Regulation	REG∟	0 A ≤ Io ≤ 0.5 A		17	50	mV
Quiescent Current	IBIAS	Io = 0 A		1.9	4.0	mA
		Io = 0.5 A		16	30	IIIA
Startup Quiescent Current	IBIAS (s)	V <sub>IN</sub> = 4.5 V, I <sub>O</sub> = 0 A		10	30	mA
		V <sub>IN</sub> = 4.5 V, I <sub>O</sub> = 0.5 A			80	IIIA
Quiescent Current Change	$\Delta I_BIAS$	$0^{\circ}C \le T_{J} \le 125^{\circ}C, 6 \text{ V} \le V_{IN} \le 16 \text{ V}$		2.4	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		87		μVr.m.s.
Ripple Rejection	R·R	f = 120 Hz, 6 V ≤ V <sub>IN</sub> ≤ 16 V	46	60		dB
Dropout Voltage	V <sub>DIF</sub>	0°C ≤ T <sub>J</sub> ≤ 125°C, lo = 0.5 A		0.5	1.0	V
Short Circuit Current	IO short	VIN = 6.5 V	0.65	1.1	1.5	Δ.
		V <sub>IN</sub> = 16 V		0.6		A
Peak Output Current	IO peak	VIN = 6.5 V	0.7	1.2	1.5	
		V <sub>IN</sub> = 16 V	0.6	1.1	1.5	Α
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}C \le T_{J} \le 125^{\circ}C$ , lo = 5 mA		0.7		mV/°C

Hounen



 $\mu$ PC29M06 (T<sub>J</sub> = 25°C, V<sub>IN</sub> = 9 V, Io = 350 mA, C<sub>IN</sub> = 0.22  $\mu$ F, C<sub>OUT</sub> = 47  $\mu$ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		5.76	6.0	6.24	
		$ \begin{array}{c} 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 7 \ V \leq V_{IN} \leq 16 \ V, \\ 0 \ A \leq I_{O} \leq 350 \ mA \end{array} $	5.70		6.30	V
		0°C ≤ TJ ≤ 125°C, 0 A ≤ lo ≤ 0.5 A				
Line Regulation	REGIN	7 V ≤ V <sub>IN</sub> ≤ 16 V		30	60	mV
Load Regulation	REG∟	0 A ≤ lo ≤ 0.5 A		30	60	mV
Quiescent Current	IBIAS	lo = 0 A		2.0	4.0	mA
		lo = 0.5 A		16	30	IIIA
Startup Quiescent Current	IBIAS (s)	V <sub>IN</sub> = 5.5 V, Io = 0 A		10	30	mA
		V <sub>IN</sub> = 5.5 V, Io = 0.5 A			80	IIIA
Quiescent Current Change	$\Delta I$ bias	0°C ≤ T <sub>J</sub> ≤ 125°C, 7 V ≤ V <sub>IN</sub> ≤ 16 V		2.5	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		126		μVr.m.s.
Ripple Rejection	R·R	f = 120 Hz, 7 V ≤ V <sub>IN</sub> ≤ 16 V	42	58		dB
Dropout Voltage	VDIF	0°C ≤ T <sub>J</sub> ≤ 125°C, lo = 0.5 A		0.5	1.0	V
Short Circuit Current	IO short	V <sub>IN</sub> = 7.5 V	0.7	1.1	1.5	Α
		V <sub>IN</sub> = 16 V	2)	0.6		
Peak Output Current	IO peak	V <sub>IN</sub> = 7.5 V	0.7	1.1	1.5	A
		V <sub>IN</sub> = 16 V	0.6	1.1	1.5	
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	0°C ≤ TJ ≤ 125°C, lo = 5 mA		0.44		mV/°C

Hotre



 $\mu$ PC29M07 (T<sub>J</sub> = 25°C, V<sub>IN</sub> = 10 V, Io = 350 mA, C<sub>IN</sub> = 0.22  $\mu$ F, Cout = 47  $\mu$ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		6.72	7.0	7.28	
		$ \begin{array}{c} 0^{\circ}C \leq T_{J} \leq 125^{\circ}C,~8~V \leq V_{IN} \leq 16~V,\\ 0~A \leq I_{O} \leq 350~mA \end{array} $	6.65		7.35	V
		$0^{\circ}C \le T_{J} \le 125^{\circ}C, \ 0 \ A \le I_{O} \le 0.5 \ A$				
Line Regulation	REGIN	8 V ≤ V <sub>IN</sub> ≤ 16 V		35	70	mV
Load Regulation	REGL	0 A ≤ Io ≤ 0.5 A		35	70	mV
Quiescent Current	IBIAS	Io = 0 A		2.0	4.0	A
		Io = 0.5 A		16	30	mA
Startup Quiescent Current	IBIAS (s)	V <sub>IN</sub> = 6.5 V, I <sub>O</sub> = 0 A		10	30	A
		V <sub>IN</sub> = 6.5 V, I <sub>O</sub> = 0.5 A			80	mA
Quiescent Current Change	ΔΙΒΙΑS	$0^{\circ}C \le T_J \le 125^{\circ}C, 8 \text{ V} \le V_{IN} \le 16 \text{ V}$		2.6	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		147		$\mu V_{r.m.s.}$
Ripple Rejection	R·R	f = 120 Hz, 8 V ≤ V <sub>IN</sub> ≤ 16 V	40	56		dB
Dropout Voltage	V <sub>DIF</sub>	0°C ≤ T <sub>J</sub> ≤ 125°C, lo = 0.5 A		0.5	1.0	V
Short Circuit Current	IO short	V <sub>IN</sub> = 8.5 V	0.7	1.1	1.5	
		V <sub>IN</sub> = 16 V		0.6		A
Peak Output Current	lo peak	VIN = 8.5 V	0.7	1.2	1.5	
		V <sub>IN</sub> = 16 V	0.6	1.1	1.5	Α
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}C \le T_{J} \le 125^{\circ}C$ , $lo = 5 \text{ mA}$		0.7		mV/°C

Holiner



 $\mu$ PC29M08 (T<sub>J</sub> = 25°C, V<sub>IN</sub> = 11 V, Io = 350 mA, C<sub>IN</sub> = 0.22  $\mu$ F, Cout = 47  $\mu$ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		7.68	8.0	8.32	
		$ 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 9 \ V \leq V_{IN} \leq 18 \ V, \\ 0 \ A \leq Io \leq 350 \ mA $	7.6		8.4	V
		$0^{\circ}C \le T_{J} \le 125^{\circ}C, \ 0 \ A \le I_{O} \le 0.5 \ A$				
Line Regulation	REGIN	9 V ≤ V <sub>IN</sub> ≤ 18 V		40	80	mV
Load Regulation	REGL	0 A ≤ Io ≤ 0.5 A		40	80	mV
Quiescent Current	IBIAS	Io = 0 A		2.0	4.0	A
		Io = 0.5 A		15	30	mA
Startup Quiescent Current	IBIAS (s)	V <sub>IN</sub> = 7.5 V, I <sub>O</sub> = 0 A		10	30	
		V <sub>IN</sub> = 7.5 V, I <sub>O</sub> = 0.5 A			80	mA
Quiescent Current Change	ΔΙΒΙΑS	0°C ≤ T <sub>J</sub> ≤ 125°C, 9 V ≤ V <sub>IN</sub> ≤ 18 V		3.0	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		150		$\mu V_{r.m.s.}$
Ripple Rejection	R·R	f = 120 Hz, 9 V ≤ V <sub>IN</sub> ≤ 18 V	42	58		dB
Dropout Voltage	V <sub>DIF</sub>	0°C ≤ T <sub>J</sub> ≤ 125°C, lo = 0.5 A		0.5	1.0	V
Short Circuit Current	IO short	V <sub>IN</sub> = 9.5 V		1.0		_
		V <sub>IN</sub> = 18 V	2)	0.55		A
Peak Output Current	lo peak	VIN = 9.5 V	0.7	1.2	1.5	_
		V <sub>IN</sub> = 18 V	0.6	1.1	1.5	Α
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	0°C ≤ T <sub>J</sub> ≤ 125°C, lo = 5 mA		0.7		mV/°C

Hotrein



 $\mu$ PC29M09 (T<sub>J</sub> = 25°C, V<sub>IN</sub> = 12 V, Io = 350 mA, C<sub>IN</sub> = 0.22  $\mu$ F, Cout = 47  $\mu$ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		8.64	9.0	9.36	
		$ \begin{array}{c} 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 10 \ V \leq V_{IN} \leq 18 \ V, \\ 0 \ A \leq Io \leq 350 \ mA \end{array} $	8.55		9.45	V
		$0^{\circ}C \le T_J \le 125^{\circ}C, \ 0 \ A \le I_0 \le 0.5 \ A$				
Line Regulation	REGIN	10 V ≤ V <sub>IN</sub> ≤ 18 V		45	90	mV
Load Regulation	REGL	0 A ≤ lo ≤ 0.5 A		45	90	mV
Quiescent Current	IBIAS	Io = 0 A		2.0	4.0	A
		lo = 0.5 A		15	30	mA
Startup Quiescent Current	IBIAS (s)	VIN = 8.5 V, Io = 0 A		10	30	^
		VIN = 8.5 V, Io = 0.5 A			80	mA
Quiescent Current Change	Δlbias	$0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 10 \ V \leq V_{IN} \leq 18 \ V$			20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		170		μVr.m.s.
Ripple Rejection	R·R	f = 120 Hz, 10 V ≤ V <sub>IN</sub> ≤ 18 V	41	57		dB
Dropout Voltage	VDIF	0°C ≤ T <sub>J</sub> ≤ 125°C, lo = 0.5 A		0.5	1.0	V
Short Circuit Current	IO short	V <sub>IN</sub> = 10.5 V		1.0		
		V <sub>IN</sub> = 18 V		0.55		A
Peak Output Current	IO peak	V <sub>IN</sub> = 10.5 V	0.7	1.2	1.5	
		V <sub>IN</sub> = 18 V	0.6	1.1	1.5	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}C \le T_{J} \le 125^{\circ}C$ , $I_{O} = 5 \text{ mA}$		0.8		mV/°C
	0					



 $\mu$ PC29M10 (T<sub>J</sub> = 25°C, V<sub>IN</sub> = 13 V, Io = 350 mA, C<sub>IN</sub> = 0.22  $\mu$ F, C<sub>OUT</sub> = 47  $\mu$ F, unless otherwise specified.)

•						
Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		9.6	10.0	10.4	
		$ \begin{array}{c} 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 11 \ V \leq V_{IN} \leq 18 \ V, \\ 0 \ A \leq Io \leq 350 \ mA \end{array} $	9.5		10.5	V
		$0^{\circ}C \le T_{J} \le 125^{\circ}C, \ 0 \ A \le Io \le 0.5 \ A$			10.4	
Line Regulation	REGIN	11 V ≤ V <sub>IN</sub> ≤ 18 V		34	100	mV
Load Regulation	REG∟	0 A ≤ lo ≤ 0.5 A		10	100	mV
Quiescent Current	IBIAS	Io = 0 A		2.1	4.0	A
		Io = 0.5 A		16	30	mA
Startup Quiescent Current	IBIAS (s)	V <sub>IN</sub> = 9.5 V, I <sub>O</sub> = 0 A		10	30	
		V <sub>IN</sub> = 9.5 V, I <sub>O</sub> = 0.5 A			80	mA
Quiescent Current Change	$\Delta I_BIAS$	$0^{\circ}C \le T_{J} \le 125^{\circ}C, \ 11 \ V \le V_{IN} \le 18 \ V$		1.9	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		180		μVr.m.s.
Ripple Rejection	R·R	f = 120 Hz, 11 V ≤ V <sub>IN</sub> ≤ 18 V	40	53		dB
Dropout Voltage	V <sub>DIF</sub>	0°C ≤ T <sub>J</sub> ≤ 125°C, lo = 0.5 A		0.5	1.0	V
Short Circuit Current	IO short	V <sub>IN</sub> = 11.5 V		0.9		
		V <sub>IN</sub> = 18 V		0.5		A
Peak Output Current	lo peak	V <sub>IN</sub> = 11.5 V	0.7	1.2	1.5	
		V <sub>IN</sub> = 18 V	0.6	1.2	1.5	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}C \leq T_{J} \leq 125^{\circ}C$ , $lo = 5 \text{ mA}$		0.9		mV/°C
40	O					

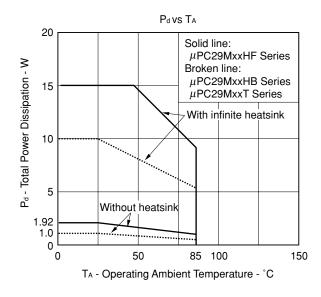


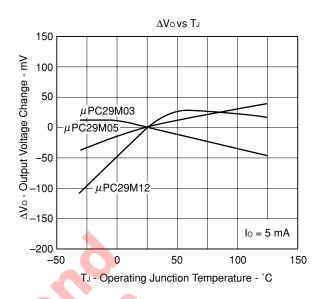
 $\mu$ PC29M12 (T<sub>J</sub> = 25°C, V<sub>IN</sub> = 15 V, Io = 350 mA, C<sub>IN</sub> = 0.22  $\mu$ F, CouT = 47  $\mu$ F, unless otherwise specified.)

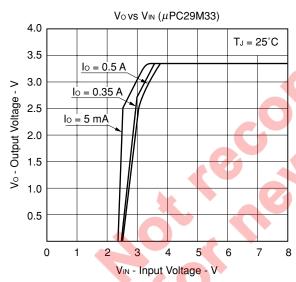
Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		11.52	12	12.48	
		$ 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 13 \ V \leq V_{IN} \leq 18 \ V, \\ 0 \ A \leq I_{O} \leq 350 \ mA $	11.4		12.6	V
		$0^{\circ}C \le T_{J} \le 125^{\circ}C, \ 0 \ A \le I_{O} \le 0.5 \ A$				
Line Regulation	REGIN	13 V ≤ V <sub>IN</sub> ≤ 18 V		25	120	mV
Load Regulation	REG∟	0 A ≤ Io ≤ 0.5 A		13	120	mV
Quiescent Current	IBIAS	Io = 0 A		2.1	4.0	A
		Io = 0.5 A		14	30	mA
Startup Quiescent Current	IBIAS (s)	Vin = 11.5 V, Io = 0 A		10	30	4
		Vin = 11.5 V, Io = 0.5 A			80	mA
Quiescent Current Change	Δlbias	$0^{\circ}C \le T_J \le 125^{\circ}C, \ 13 \ V \le V_{IN} \le 18 \ V$		1.7	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		210		μVr.m.s.
Ripple Rejection	R·R	f = 120 Hz, 13 V ≤ V <sub>IN</sub> ≤ 18 V	40	53		dB
Dropout Voltage	V <sub>DIF</sub>	0°C ≤ TJ ≤ 125°C, lo = 0.5 A		0.5	1.0	V
Short Circuit Current	IO short	V <sub>IN</sub> = 14 V		0.7		
		V <sub>IN</sub> = 18 V		0.5		A
Peak Output Current	IO peak	V <sub>IN</sub> = 14 V	0.7	1.2	1.5	
		V <sub>IN</sub> = 18 V	0.6	1.1	1.5	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}C \le T_{J} \le 125^{\circ}C$ , lo = 5 mA		1.2		mV/°C

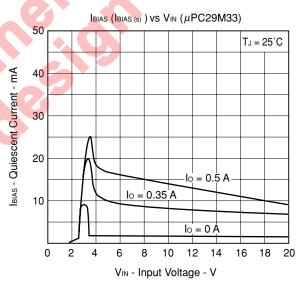
Hotren

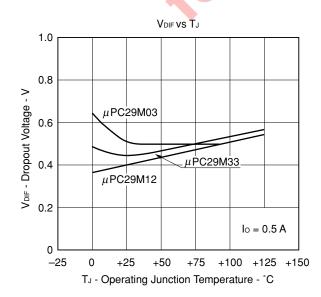
#### TYPICAL CHARACTERISTICS

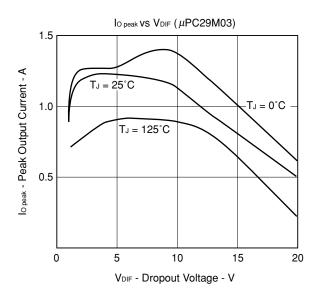




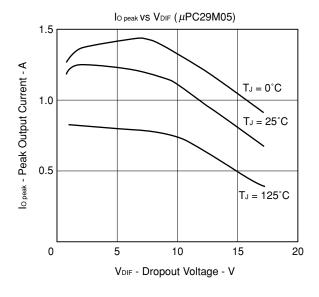


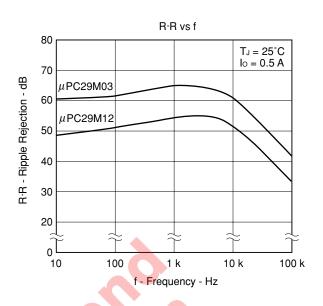


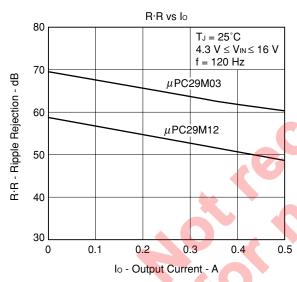


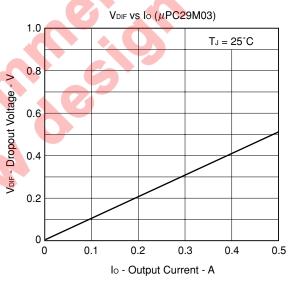


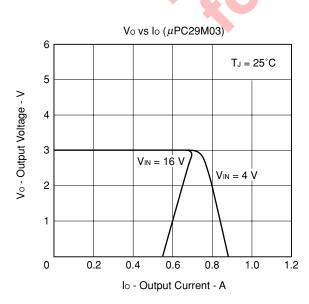








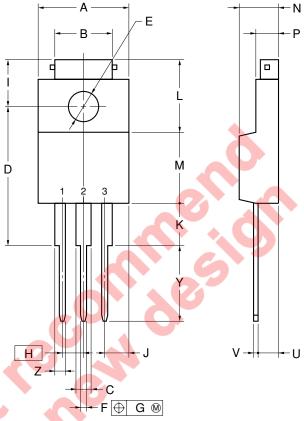




#### **PACKAGE DRAWINGS**

 $\mu$ PC29MxxHF Series

### 3PIN PLASTIC SIP (MP-45G)



#### NOTE

Each lead centerline is located within 0.25 mm of its true position (T.P.) at maximum material condition.

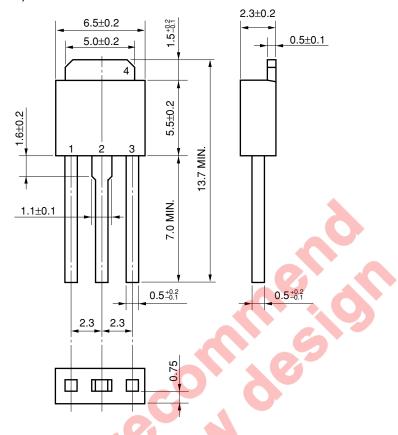
ITEM	MILLIMETERS
Α	10.0±0.2
В	7.0±0.2
С	1.50±0.2
D	17.0±0.3
Е	φ3.3±0.2
F	0.75±0.10
G	0.25
Н	2.54 (T.P.)
I	5.0±0.3
J	2.46±0.2
K	5.0±0.2
L	8.5±0.2
М	8.5±0.2
N	4.5±0.2
Р	2.8±0.2
U	2.4±0.5
V	0.65±0.10
Υ	8.9±0.7
Z	1.30±0.2
	DOLLE OF 4D

P3HF-254B-4



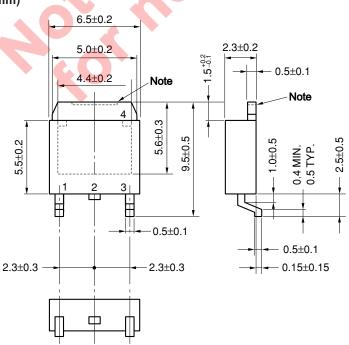
#### $\mu$ PC29MxxHB Series

SC-64 (MP-3) (Unit: mm)



 $\mu$ PC29MxxT Series

<R> SC-63 (MP-3Z) (Unit: mm)



Note The depth of notch at the top of the fin is from 0 to 0.2 mm.



#### <R> RECOMMENDED SOLDERING CONDITIONS

When soldering this product, it is highly recommended to observe the conditions as shown below. If other soldering processes are used, or if the soldering is performed under different condition, please make sure to consult with our sales offices.

For more details, refer to the **Semiconductor Device Mount Manual** (http://www.necel.com/pkg/en/mount/index.html)

#### Surface mount devices

 $\mu$ PC29MxxT Series: SC-63 (MP-3Z)

Process	Conditions	Symbol
Infrared ray reflow	Peak temperature: 235°C or below (Package surface temperature), Reflow time: 30 seconds or less (at 210°C or higher), Maximum number of reflow processes: 3 times or less.	IR35-00-3
VPS	Peak temperature: 215°C or below (Package surface temperature), Reflow time: 40 seconds or less (at 200°C or higher), Maximum number of reflow processes: 3 times or less.	VP15-00-3
Partial heating method	Pin temperature: 350°C or below, Heat time: 3 seconds or less (Per each side of the device).	P350

Caution Apply only one kind of soldering condition to a device, except for "partial heating method", or the device will be damaged by heat stress.

Remark Flux: Rosin-based flux sith low chlorine content (chlorine 0.2 Wt% or below) is recommended.

μPC29MxxT-AZ Series Note1, μPC29MxxT-AY Series Note2: SC-63 (MP-3Z)

Process	Conditions	Symbol
Infrared ray reflow	Peak temperature: 260°C or below (Package surface temperature), Reflow time: 60 seconds or less (at 220°C or higher), Maximum number of reflow processes: 3 times or less.	IR60-00-3
Partial heating method	Pin temperature: 350°C or below,  Heat time: 3 seconds or less (Per each side of the device).	P350

Notes 1. Pb-free (This product does not contain Pb in the external electrode.)

2. Pb-free (This product does not contain Pb in the external electrode, Sn100% plating.)

Caution Apply only one kind of soldering condition to a device, except for "partial heating method", or the device will be damaged by heat stress.

Remark Flux: Rosin-based flux sith low chlorine content (chlorine 0.2 Wt% or below) is recommended.



#### Through-hole devices

μPC29MxxHF Series, μPC29MxxHF-AZ Series Note1: Isolated TO-220 (MP-45G)

μPC29MxxHB Series, μPC29MxxHB-AZ Series Note1, μPC29MxxHB-AY Series Note2: SC-64 (MP-3)

Process	Conditions	Symbol
Wave soldering (only to leads)	Solder temperature: 260°C or below, Flow time: 10 seconds or less.	WS60-00-1
Partial heating method	Pin temperature: 350°C or below, Heat time: 3 seconds or less (Per each pin).	P350

**Notes 1.** Pb-free (This product does not contain Pb in the external electrode.)

2. Pb-free (This product does not contain Pb in the external electrode, Sn100% plating.)

Caution For through-hole device, the wave soldering process must be applied only to leads, and make sure that the package body does not get jet soldered.

#### **CAUTION ON USE**

When using the  $\mu$ PC29Mxx series at the input voltage which is lower than in the recommended operating condition, the high quiescent current flows through devices because the transistor of the output paragraph is saturated (Refer to "IBIAS (IBIAS (s)) vs VIN curves in TYPICAL CHARACTERISTICS"). The  $\mu$ PC29Mxx series have saturation protection circuits, but they sometimes need about 80 mA current. Therefore the power supply on the input needs the enough current capacity to pass this quiescent current when the devices startup.

#### <R> REFERENCE DOCUMENTS

USER'S MANUAL USAGE OF THREE TERMINAL REGULATORS
REVIEW OF QUALITY AND RELIABILITY HANDBOOK
INFORMATION VOLTAGE REGULATOR OF SMD
SEMICONDUCTOR DEVICE MOUNT MANUAL

Document No.G12702E
Document No.C12769E
Document No.G11872E
http://www.necel.com/pkg/en/mount/index.html

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